

# ANTREX Electronics

## Electronic Components Sourcing Information

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### Product Reference Information

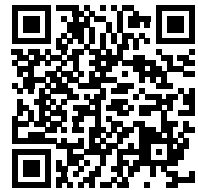
**Part Number:** SQJ402EP-T1\_BE3  
**Manufacturer:** Vishay Siliconix  
**Package:** Please confirm with sales  
**Availability:** Please confirm with sales

**Product Page:**

<https://antrexco.com/product/details/vishay-siliconix/sqj402ep-t1-be3.html>

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New & Original Components

Supplier verification and packaging condition review

CoC / RoHS / REACH documents available on request

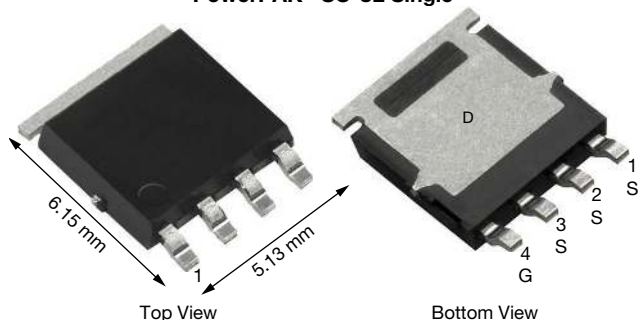
Secure sourcing support for OEM / EMS projects

**Note:**

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.

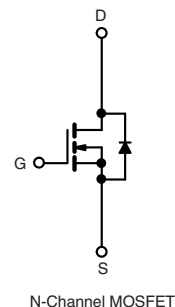
# Automotive N-Channel 100 V (D-S) 175 °C MOSFET

**PowerPAK® SO-8L Single**


## FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 %  $R_g$  and UIS tested
- Material categorization:  
for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

AUTOMOTIVE  
GRADE

**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**


| PRODUCT SUMMARY                               |        |
|-----------------------------------------------|--------|
| $V_{DS}$ (V)                                  | 100    |
| $R_{DS(on)}$ ( $\Omega$ ) at $V_{GS} = 10$ V  | 0.0110 |
| $R_{DS(on)}$ ( $\Omega$ ) at $V_{GS} = 4.5$ V | 0.0140 |
| $I_D$ (A)                                     | 32     |
| Configuration                                 | Single |

| ORDERING INFORMATION            |                                                                                                                            |
|---------------------------------|----------------------------------------------------------------------------------------------------------------------------|
| Package                         | PowerPAK SO-8L                                                                                                             |
| Lead (Pb)-free and halogen-free | SQJ402EP<br>(for detailed order number please see <a href="http://www.vishay.com/doc?79771">www.vishay.com/doc?79771</a> ) |

| ABSOLUTE MAXIMUM RATINGS ( $T_C = 25$ °C, unless otherwise noted) |                |                |             |      |
|-------------------------------------------------------------------|----------------|----------------|-------------|------|
| PARAMETER                                                         |                | SYMBOL         | LIMIT       | UNIT |
| Drain-source voltage                                              |                | $V_{DS}$       | 100         | V    |
| Gate-source voltage                                               |                | $V_{GS}$       | $\pm 20$    |      |
| Continuous drain current <sup>a</sup>                             | $T_C = 25$ °C  | $I_D$          | 32          | A    |
|                                                                   | $T_C = 125$ °C |                | 32          |      |
| Continuous source current (diode conduction) <sup>a</sup>         |                | $I_S$          | 32          |      |
| Pulsed drain current <sup>b</sup>                                 |                | $I_{DM}$       | 75          |      |
| Single pulse avalanche current                                    | L = 0.1 mH     | $I_{AS}$       | 31          | mJ   |
| Single pulse avalanche energy                                     |                | $E_{AS}$       | 48          |      |
| Maximum power dissipation                                         | $T_C = 25$ °C  | $P_D$          | 83          | W    |
|                                                                   | $T_C = 125$ °C |                | 27          |      |
| Operating junction and storage temperature range                  |                | $T_J, T_{stg}$ | -55 to +175 | °C   |
| Soldering recommendations (peak temperature) <sup>d</sup>         |                |                | 260         |      |

| THERMAL RESISTANCE RATINGS |                        |            |       |      |
|----------------------------|------------------------|------------|-------|------|
| PARAMETER                  |                        | SYMBOL     | LIMIT | UNIT |
| Junction-to-ambient        | PCB mount <sup>c</sup> | $R_{thJA}$ | 65    | °C/W |
| Junction-to-case (drain)   |                        | $R_{thJC}$ | 1.8   |      |

## Notes

- Package limited
- Pulse test; pulse width  $\leq 300$   $\mu$ s, duty cycle  $\leq 2$  %
- When mounted on 1" square PCB (FR-4 material)
- See solder profile ([www.vishay.com/doc?73257](http://www.vishay.com/doc?73257)). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

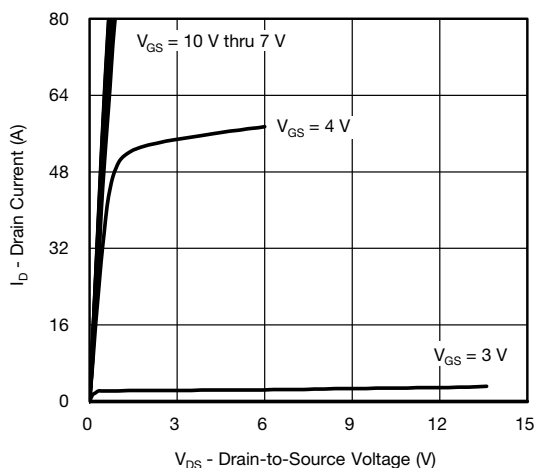
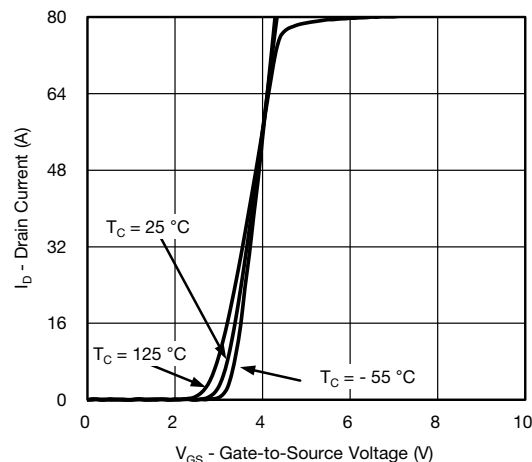
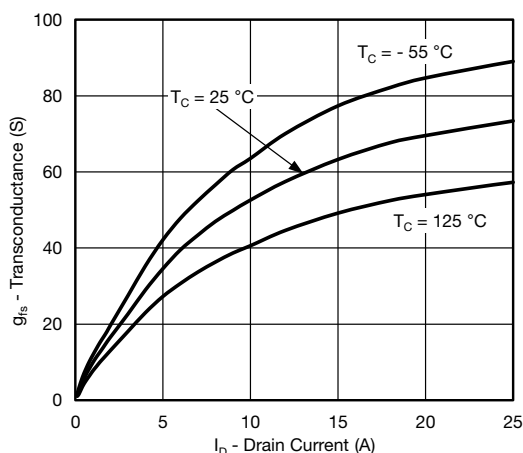
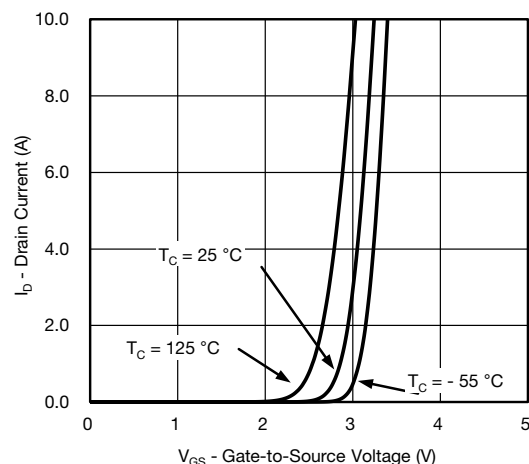
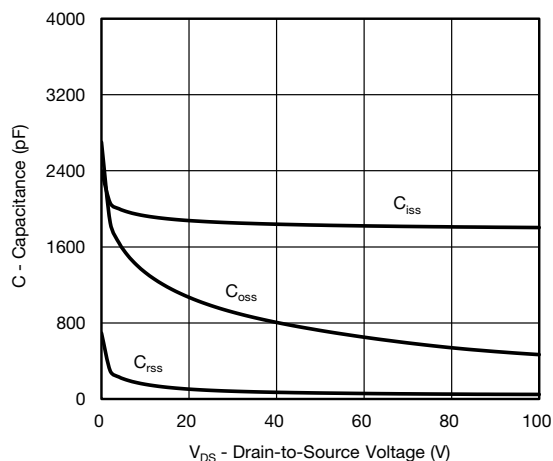
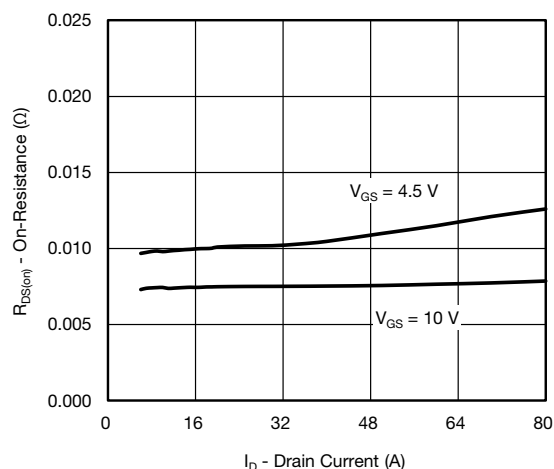


| SPECIFICATIONS (T <sub>C</sub> = 25 °C, unless otherwise noted) |                     |                                                                                                                      |                                                  |      |        |        |      |
|-----------------------------------------------------------------|---------------------|----------------------------------------------------------------------------------------------------------------------|--------------------------------------------------|------|--------|--------|------|
| PARAMETER                                                       | SYMBOL              | TEST CONDITIONS                                                                                                      |                                                  | MIN. | TYP.   | MAX.   | UNIT |
| Static                                                          |                     |                                                                                                                      |                                                  |      |        |        |      |
| Drain-source breakdown voltage                                  | V <sub>DS</sub>     | V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA                                                                       |                                                  | 100  | -      | -      | V    |
| Gate-source threshold voltage                                   | V <sub>GS(th)</sub> | V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA                                                          |                                                  | 1.5  | 2.0    | 2.5    |      |
| Gate-source leakage                                             | I <sub>GSS</sub>    | V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ± 20 V                                                                      |                                                  | -    | -      | ± 100  | nA   |
| Zero gate voltage drain current                                 | I <sub>DSS</sub>    | V <sub>GS</sub> = 0 V                                                                                                | V <sub>DS</sub> = 100 V                          | -    | -      | 1      | μA   |
|                                                                 |                     | V <sub>GS</sub> = 0 V                                                                                                | V <sub>DS</sub> = 100 V, T <sub>J</sub> = 125 °C | -    | -      | 50     |      |
|                                                                 |                     | V <sub>GS</sub> = 0 V                                                                                                | V <sub>DS</sub> = 100 V, T <sub>J</sub> = 175 °C | -    | -      | 150    |      |
| On-state drain current <sup>a</sup>                             | I <sub>D(on)</sub>  | V <sub>GS</sub> = 10 V                                                                                               | V <sub>DS</sub> ≥ 5 V                            | 30   | -      | -      | A    |
| Drain-source on-state resistance <sup>a</sup>                   | R <sub>DS(on)</sub> | V <sub>GS</sub> = 10 V                                                                                               | I <sub>D</sub> = 10.7 A                          | -    | 0.0090 | 0.0110 | Ω    |
|                                                                 |                     | V <sub>GS</sub> = 10 V                                                                                               | I <sub>D</sub> = 10.7 A, T <sub>J</sub> = 125 °C | -    | -      | 0.0170 |      |
|                                                                 |                     | V <sub>GS</sub> = 10 V                                                                                               | I <sub>D</sub> = 10.7 A, T <sub>J</sub> = 175 °C | -    | -      | 0.0210 |      |
|                                                                 |                     | V <sub>GS</sub> = 4.5 V                                                                                              | I <sub>D</sub> = 9.5 A                           | -    | 0.0115 | 0.0140 |      |
| Forward transconductance <sup>b</sup>                           | g <sub>fs</sub>     | V <sub>DS</sub> = 15 V, I <sub>D</sub> = 10.7 A                                                                      |                                                  | -    | 54     | -      | S    |
| Dynamic <sup>b</sup>                                            |                     |                                                                                                                      |                                                  |      |        |        |      |
| Input capacitance                                               | C <sub>iss</sub>    | V <sub>GS</sub> = 0 V                                                                                                | V <sub>DS</sub> = 25 V, f = 1 MHz                | -    | 1829   | 2286   | pF   |
| Output capacitance                                              | C <sub>oss</sub>    |                                                                                                                      |                                                  | -    | 722    | 903    |      |
| Reverse transfer capacitance                                    | C <sub>rss</sub>    |                                                                                                                      |                                                  | -    | 62     | 78     |      |
| Total gate charge <sup>c</sup>                                  | Q <sub>g</sub>      | V <sub>GS</sub> = 10 V                                                                                               | V <sub>DS</sub> = 50 V, I <sub>D</sub> = 10 A    | -    | 34     | 51     | nC   |
| Gate-source charge <sup>c</sup>                                 | Q <sub>gs</sub>     |                                                                                                                      |                                                  | -    | 6      | -      |      |
| Gate-drain charge <sup>c</sup>                                  | Q <sub>gd</sub>     |                                                                                                                      |                                                  | -    | 13     | -      |      |
| Gate resistance                                                 | R <sub>g</sub>      | f = 1 MHz                                                                                                            |                                                  | 0.65 | 1.39   | 2      | Ω    |
| Turn-on delay time <sup>c</sup>                                 | t <sub>d(on)</sub>  | V <sub>DD</sub> = 50 V, R <sub>L</sub> = 5 Ω<br>I <sub>D</sub> ≅ 10 A, V <sub>GEN</sub> = 10 V, R <sub>g</sub> = 1 Ω |                                                  | -    | 10     | 15     | ns   |
| Rise time <sup>c</sup>                                          | t <sub>r</sub>      |                                                                                                                      |                                                  | -    | 10     | 15     |      |
| Turn-off delay time <sup>c</sup>                                | t <sub>d(off)</sub> |                                                                                                                      |                                                  | -    | 27     | 40     |      |
| Fall time <sup>c</sup>                                          | t <sub>f</sub>      |                                                                                                                      |                                                  | -    | 7      | 11     |      |
| Source-Drain Diode Ratings and Characteristics <sup>b</sup>     |                     |                                                                                                                      |                                                  |      |        |        |      |
| Pulsed current <sup>a</sup>                                     | I <sub>SM</sub>     |                                                                                                                      |                                                  | -    | -      | 75     | A    |
| Forward voltage                                                 | V <sub>SD</sub>     | I <sub>F</sub> = 7 A, V <sub>GS</sub> = 0 V                                                                          |                                                  | -    | 0.77   | 1.2    | V    |

**Notes**

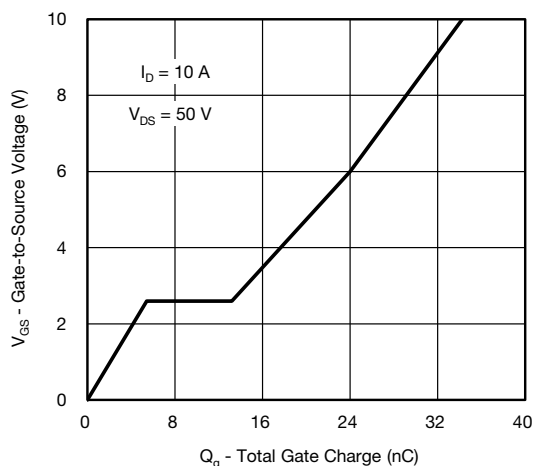
- a. Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$   
b. Guaranteed by design, not subject to production testing  
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

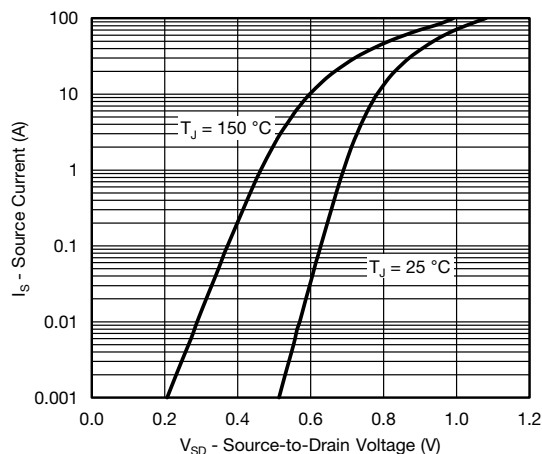
**TYPICAL CHARACTERISTICS** ( $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise noted)

**Output Characteristics**

**Transfer Characteristics**

**Transconductance**

**Transfer Characteristics**

**Capacitance**

**On-Resistance vs. Drain Current**



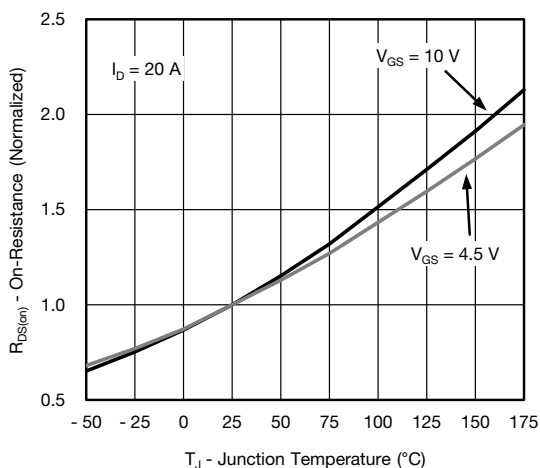
**TYPICAL CHARACTERISTICS** ( $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise noted)



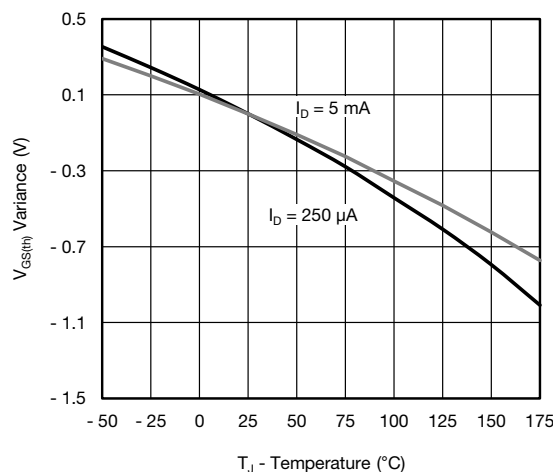
**Gate Charge**



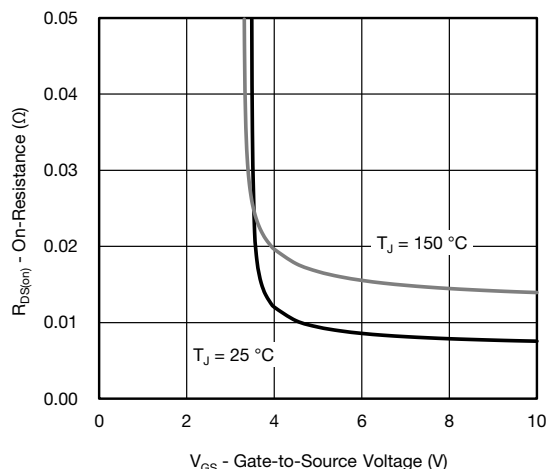
**Source Drain Diode Forward Voltage**



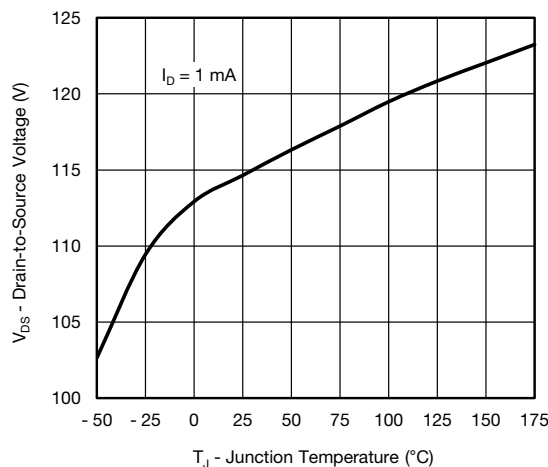
**On-Resistance vs. Junction Temperature**



**Threshold Voltage**



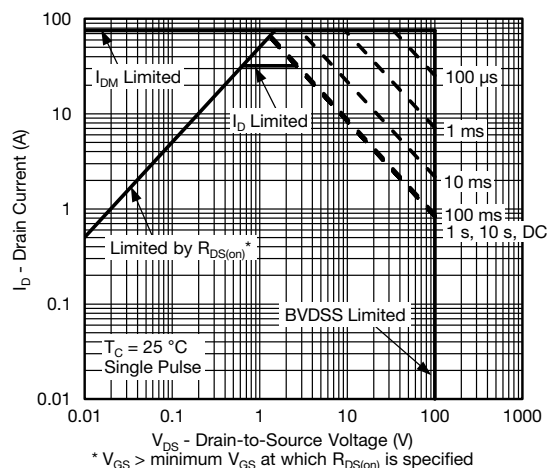
**On-Resistance vs. Gate-to-Source Voltage**



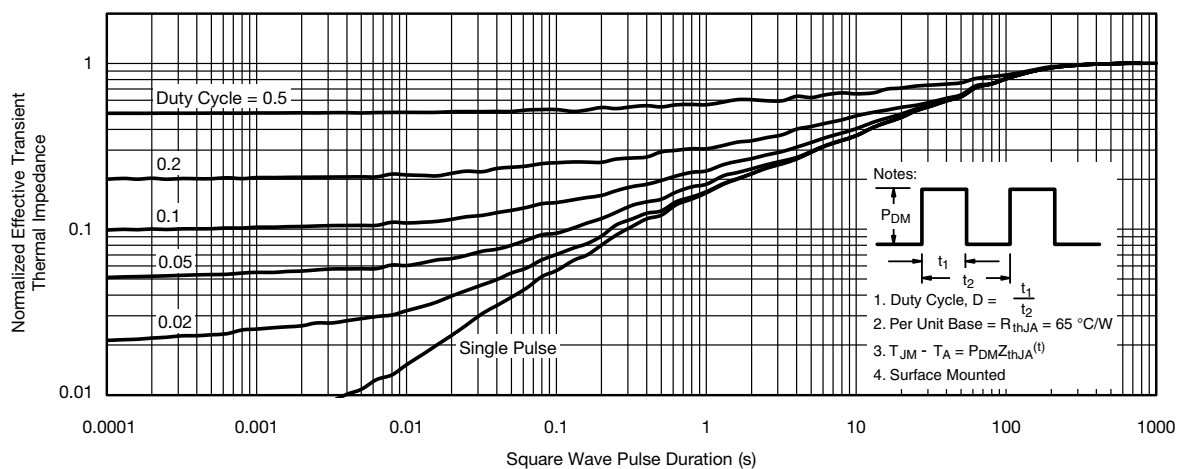
**Drain Source Breakdown vs. Junction Temperature**



**THERMAL RATINGS** ( $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise noted)



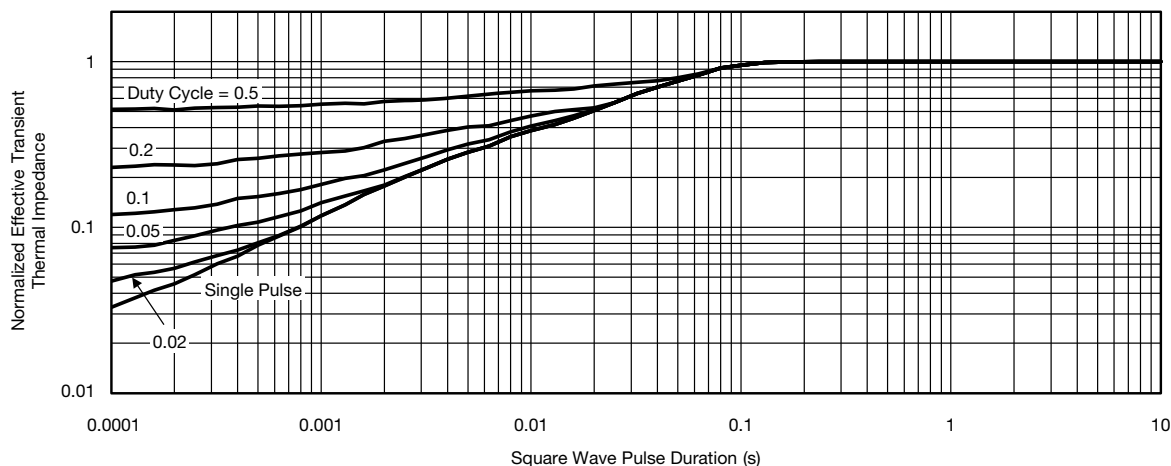
**Safe Operating Area**



**Normalized Thermal Transient Impedance, Junction-to-Ambient**



**THERMAL RATINGS** ( $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise noted)



**Normalized Thermal Transient Impedance, Junction-to-Case**

**Note**

- The characteristics shown in the two graphs
  - Normalized transient thermal impedance junction-to-ambient ( $25\text{ }^{\circ}\text{C}$ )
  - Normalized transient thermal impedance junction-to-case ( $25\text{ }^{\circ}\text{C}$ )are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see [www.vishay.com/ppg?267997](http://www.vishay.com/ppg?267997).



## PowerPAK® SO-8L Case Outline 2





| DIM.                                           | MILLIMETERS |      |       | INCHES    |       |       |
|------------------------------------------------|-------------|------|-------|-----------|-------|-------|
|                                                | MIN.        | NOM. | MAX.  | MIN.      | NOM.  | MAX.  |
| A                                              | 1.00        | 1.07 | 1.14  | 0.039     | 0.042 | 0.045 |
| A1                                             | 0.00        | -    | 0.127 | 0.00      | -     | 0.005 |
| b                                              | 0.33        | 0.41 | 0.48  | 0.013     | 0.016 | 0.019 |
| b1                                             | 0.44        | 0.51 | 0.58  | 0.017     | 0.020 | 0.023 |
| b2                                             | 4.80        | 4.90 | 5.00  | 0.189     | 0.193 | 0.197 |
| b3                                             | 0.094       |      |       | 0.004     |       |       |
| b4                                             | 0.47        |      |       | 0.019     |       |       |
| c                                              | 0.20        | 0.25 | 0.30  | 0.008     | 0.010 | 0.012 |
| D                                              | 5.00        | 5.13 | 5.25  | 0.197     | 0.202 | 0.207 |
| D1                                             | 4.80        | 4.90 | 5.00  | 0.189     | 0.193 | 0.197 |
| D2                                             | 3.86        | 3.96 | 4.06  | 0.152     | 0.156 | 0.160 |
| D3                                             | 1.63        | 1.73 | 1.83  | 0.064     | 0.068 | 0.072 |
| e                                              | 1.27 BSC    |      |       | 0.050 BSC |       |       |
| E                                              | 6.05        | 6.15 | 6.25  | 0.238     | 0.242 | 0.246 |
| E1                                             | 4.27        | 4.37 | 4.47  | 0.168     | 0.172 | 0.176 |
| E2                                             | 2.75        | 2.85 | 2.95  | 0.108     | 0.112 | 0.116 |
| E3                                             | 6.05        | 6.22 | 6.40  | 0.238     | 0.245 | 0.252 |
| F                                              | -           | -    | 0.15  | -         | -     | 0.006 |
| L                                              | 0.62        | 0.72 | 0.82  | 0.024     | 0.028 | 0.032 |
| L1                                             | 0.92        | 1.07 | 1.22  | 0.036     | 0.042 | 0.048 |
| K                                              | 0.51        |      |       | 0.020     |       |       |
| W                                              | 0.23        |      |       | 0.009     |       |       |
| W1                                             | 0.41        |      |       | 0.016     |       |       |
| W2                                             | 2.82        |      |       | 0.111     |       |       |
| W3                                             | 2.96        |      |       | 0.117     |       |       |
| θ                                              | 0°          | -    | 10°   | 0°        | -     | 10°   |
| ECN: C23-1026-Rev. D, 25-Sep-2023<br>DWG: 6044 |             |      |       |           |       |       |

**Note**

- Millimeters will govern



## RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L SINGLE



Recommended Minimum Pads  
Dimensions in mm (inches)



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